## NSN 5961-01-333-1446

Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-333-1446 **Inclosure Material:** Metal **Overall Length:** Between 0.895 inches and 0.905 inches **Overall Height:** Between 0.205 inches and 0.219 inches **Overall Width:** Between 0.395 inches and 0.405 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 drain to source voltage and 12.0 gate to source voltage **Current Rating Per Characteristic:** 5.00 amperes drain current **Power Rating Per Characteristic:** 58.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No